

### INTEGRATED COMPLEMENTARY BUFFERED-GATE SCRS FOR DUAL POLARITY SLIC OVERVOLTAGE PROTECTION

# TISP9110MDM Overvoltage Protector

High Performance Protection for SLICs with +ve and -ve Battery Supplies

- Wide -110 V to +110 V Programming Range
- Low 5 mA max. Gate Triggering Current
- Dynamic Protection Performance Specified for
- International Surge Waveshapes

Applications include:

- Wireless Local Loop
- Access Equipment
- Regenerated POTS
- VOIP Applications

#### **Rated for International Surge Wave Shapes**

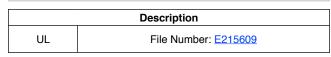
| Wave Shape | Standard         | I <sub>PPSM</sub><br>A |
|------------|------------------|------------------------|
| 2/10       | GR-1089-CORE     | 150                    |
| 10/700     | ITU-T K.20/21/45 | 80                     |
| 10/1000    | GR-1089-CORE     | 50                     |

#### Description

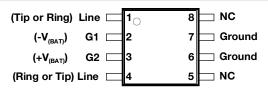
The Model TISP9110MDM is a programmable overvoltage protection device designed to protect modern dual polarity supply rail ringing SLICs (Subscriber Line Interface Circuits) against overvoltages on the telephone line. Overvoltages can be caused by lightning, a.c. power contact and induction. Four separate protection structures are used; two positive and two negative to provide optimum protection during Metallic (Differential) and Longitudinal (Common Mode) protection conditions in both polarities. Dynamic protection performance is specified under typical international surge waveforms from Telcordia GR-1089-CORE, ITU-T K.44 and YD/T 950.

The Model TISP9110MDM is programmed by connecting the G1 and G2 gate terminals to the negative (-V<sub>(BAT)</sub>) and positive (+V<sub>(BAT)</sub>) SLIC Battery supplies respectively. This creates a protector operating at typically +1.4 V above +V<sub>(BAT)</sub> and -1.4 V below -V<sub>(BAT)</sub> under a.c. power induction and power contact conditions.

Agency Recognition



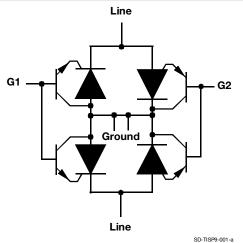
#### 8-SOIC (210 mil) Package (Top View)



NC - No internal connection Terminal typical application names shown in parenthesis

#### MD-8SOIC(210)-003-a

### **Device Symbol**



The protector gate circuitry incorporates 4 separate buffer transistors designed to provide independent control for each protection element. The gate buffer transistors minimize supply regulation issues by reducing the gate current drawn to around 5 mA, while the high voltage base emitter structures eliminate the need for expensive reverse bias protection gate diodes.

The Model TISP9110MDM is rated for common surges contained in regulatory requirements such as ITU-T K.20, K.45, Telcordia GR-1089-CORE, YD/T 950. With the use of appropriate overcurrent protection devices such as the Bourns<sup>®</sup> Multifuse<sup>®</sup> and Telefuse<sup>™</sup> devices, circuits can be designed to comply with modern telecom standards.

#### How To Order

| Device      | Package          | Carrier              | Order As       | Marking Code | Standard Quantity |
|-------------|------------------|----------------------|----------------|--------------|-------------------|
| TISP9110MDM | 8-SOIC (210 mil) | Embossed Tape Reeled | TISP9110MDMR-S | 9110M        | 2000              |



WARNING Cancer and Reproductive Harm www.P65Warnings.ca.gov

#### APRIL 2013 - REVISED JULY 2019

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#### Absolute Maximum Ratings, T<sub>A</sub> = 25 °C (Unless Otherwise Noted)

| Rating   | Symbol              | Value       | Unit |  |
|--|---------------------|-------------|------|--|
| Repetitive peak off-state voltage  |                     |             |      |  |
| $V_{G1(Line)} = 0, V_{G2} \ge +5 V$  | V <sub>DRM</sub>    | -120        | V    |  |
| $V_{G2(Line)} = 0, V_{G1} \ge -5 V$  |                     | +120        |      |  |
| Non-repetitive peak impulse current (see Notes 1, 2, 3 and 4)                      |                     |             |      |  |
| 2/10 μs (Telcordia GR-1089-CORE)   |                     | ±150        |      |  |
| 5/310 µs (ITU-T K.20, K.21 & K.45, K.44 open-circuit voltage wave shape 10/700 ms) | I <sub>PPSM</sub>   | ±80         | Α    |  |
| 10/1000 μs (Telcordia GR-1089-CORE)  |                     | ±50         |      |  |
| Non-repetitive peak on-state current, 50 Hz / 60 Hz (see Notes 1, 2, 3 and 5)      |                     |             |      |  |
| 0.2 s  |                     | 9.0         |      |  |
| 1s   | I <sub>TSM</sub>    | 5.0         | А    |  |
| 900 s  |                     | 1.7         |      |  |
| Maximum negative battery supply voltage  | V <sub>G1M</sub>    | -110        | V    |  |
| Maximum positive battery supply voltage  | V <sub>G2M</sub>    | +110        | V    |  |
| Maximum differential battery supply voltage  | $\Delta V_{(BAT)M}$ | 220         | V    |  |
| Junction temperature   | TJ                  | -40 to +150 | °C   |  |
| Storage temperature range  | T <sub>stg</sub>    | -65 to +150 | °C   |  |

NOTES: 1. Initially the device must be in thermal equilibrium with T<sub>J</sub> = 25 °C. The surge may be repeated after the device returns to its initial conditions.

2. The rated current values may be applied to either of the Line to Ground terminal pairs. Additionally, both terminal pairs may have their rated current values applied simultaneously (in this case the Ground terminal current will be twice the rated current value of a single terminal pair).

3. Rated currents only apply if pins 6 & 7 (Ground) are connected together.

4. Applies for the following bias conditions:  $V_{G1}$  = -20 V to -110 V,  $V_{G2}$  = 0 V to +110 V.

5. EIA/JESD51-2 environment and EIA/JESD51-7 high effective thermal conductivity test board (multi-layer) connected with 0.6 mm printed wiring track widths.

#### Electrical Characteristics for any Section, T<sub>A</sub> = 25 °C (Unless Otherwise Noted)

| Parameter             |                                       | Test Conditions  |  | Min  | Тур | Max        | Unit |
|-----------------------|---------------------------------------|--|--|------|-----|------------|------|
| la la                 | Off-state current                     | $V_D = V_{DRM}, V_{G1(Line)} = 0, V_{G2} \ge +5 V$   | T <sub>A</sub> = 25 °C<br>T <sub>A</sub> = 85 °C |      |     | -5<br>-50  | μA   |
| ID                    |                                       | $V_D = V_{DRM}, V_{G2(Line)} = 0, V_{G1} \ge -5 V$   | T <sub>A</sub> = 25 °C<br>T <sub>A</sub> = 85 °C |      |     | +5<br>+50  | μη   |
| I <sub>G1(Line)</sub> | Negative-gate leakage current         | V <sub>G1(Line)</sub> = -220 V   |  |      |     | - 5        | μA   |
| I <sub>G2(Line)</sub> | Positive-gate leakage current         | V <sub>G2(Line)</sub> = +220 V   |  |      |     | +5         | μA   |
| V <sub>G1L(BO)</sub>  | Gate - Line impulse breakover voltage | V <sub>G1</sub> = -100 V, I <sub>T</sub> = -100 A (see Note 6)<br>V <sub>G1</sub> = -100 V, I <sub>T</sub> = -30 A | 2/10 μs<br>10/1000 μs                            |      |     | -15<br>-11 | v    |
| V <sub>G2L(BO)</sub>  | Gate - Line impulse breakover voltage | V <sub>G2</sub> = +100 V, I <sub>T</sub> = +100 A (see Note 6)<br>V <sub>G2</sub> = +100 V, I <sub>T</sub> = +30 A | 2/10 μs<br>10/1000 μs                            |      |     | +15<br>+11 | v    |
| I <sub>H</sub> -      | Negative holding current              | V <sub>G1</sub> = -60 V, I <sub>T</sub> = -1 A, di/dt = 1 A/ms   |  | -150 |     |            | mA   |
| I <sub>G1T</sub>      | Negative-gate trigger current         | $I_{T} = -5 \text{ A,t }_{p(g)} \ge 20 \ \mu \text{s}, \ V_{G1} = -60 \text{ V}$                                   |  |      |     | + 5        | mA   |
| I <sub>G2T</sub>      | Positive-gate trigger current         | $I_T = 5 \text{ A,t }_{p(g)} \ge 20 \ \mu \text{s}, \ V_{G2} = 60 \text{ V}$                                       |  |      |     | - 5        | mA   |
| C <sub>O</sub>        | Line - Ground off-state capacitance   | f = 1 MHz, V <sub>D</sub> = -3 V, G1 & G2 open circuit   |  |      | 33  |            | pF   |

NOTE: 6. Voltage measurements should be made with an oscillosc ope with limited bandwidth (20 MHz) to avoid high frequency noise.

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### Thermal Characteristics, T<sub>A</sub> = 25 °C (Unless Otherwise Noted)

|                | Parameter | Test Conditions  | Min | Тур | Max | Unit |
|----------------|-----------|--|-----|-----|-----|------|
| $R_{\thetaJA}$ |           | EIA/JESD51-7 PCB, EIA/JESD51-2 Environment, P <sub>TOT</sub> = 4 W<br>(See Note 7) |     | 55  |     | °C/W |

NOTE 7. EIA/JESD51-7 high effective thermal conductivity test board (multi-layer) connected with 0.6 mm printed wiring track widths.

#### **Parameter Measurement Information**

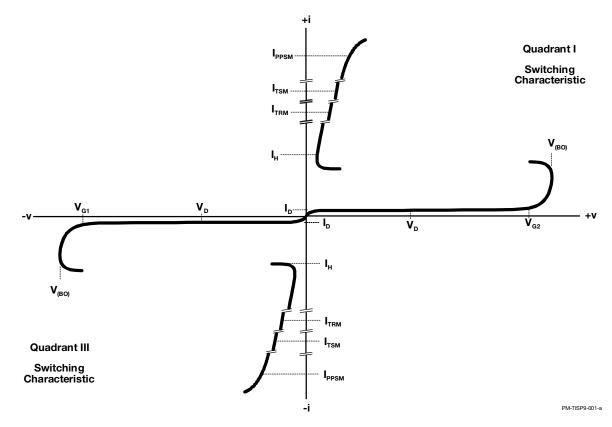
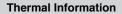


Figure 1. Voltage-Current Characteristic Unless Otherwise Noted, All Voltages are Referenced to the Ground Terminal

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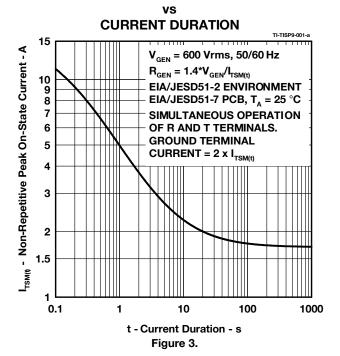
**Typical Characteristics** 



### **OFF-STATE CAPACITANCE** vs **OFF-STATE VOLTAGE** 50 45 C<sub>o</sub> - Off-state Capacitance - pF 40 35 30 25 20 T<sub>.1</sub> = 25 °C 15 V<sub>d</sub> = 1 Vrms | | | |10 0.1 100 10 1 V<sub>p</sub> - Off-state Voltage - V

Figure 2.

NON-REPETITIVE PEAK ON-STATE CURRENT

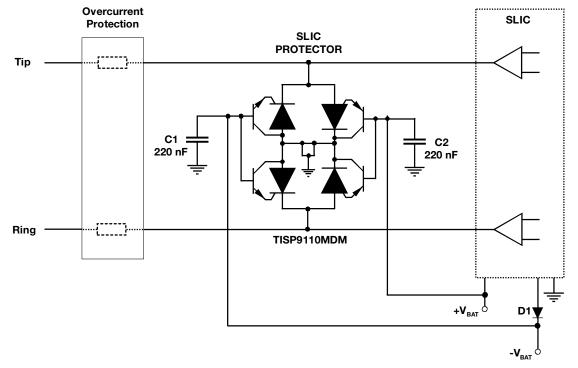


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**APPLICATIONS INFORMATION** 



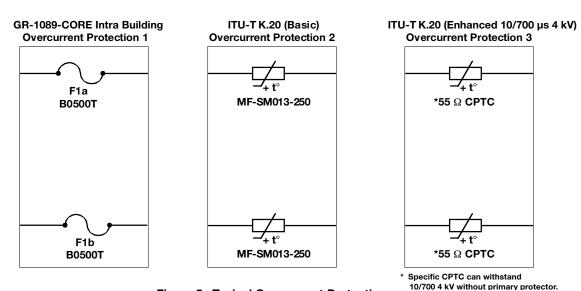


Figure 5. Typical Overcurrent Protection

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